

### Vishay Semiconductors

COMPLIANT

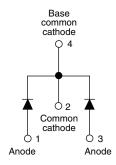
HALOGEN

FREE

## Ultrafast Rectifier, 2 x 3 A FRED Pt®



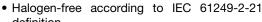
D-PAK (TO-252AA)



PRODUCT SUMMARY					
Package	D-PAK (TO-252AA)				
I <sub>F(AV)</sub>	2 x 3 A				
V <sub>R</sub>	200 V				
V <sub>F</sub> at I <sub>F</sub>	1.0 V				
t <sub>rr</sub> typ.	See Recovery table				
T <sub>J</sub> max.	175 °C				
Diode variation	Common cathode				

#### **FEATURES**

- · Ultrafast recovery time
- · Low forward voltage drop
- · Low leakage current
- 175 °C operating junction temperature
- Compliant to RoHS Directive 2002/95/EC







#### **DESCRIPTION/APPLICATIONS**

VS-MURD620CT-M3 is the state of the art ultrafast recovery rectifier specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Peak repetitive reverse voltage	$V_{RRM}$		200	V			
Average rectified forward current per device	I <sub>F(AV)</sub>	Total device, rated V <sub>R</sub> , T <sub>C</sub> = 146 °C	6				
Non-repetitive peak surge current	I <sub>FSM</sub>		50	Α			
Peak repetitive forward current per diode	I <sub>FM</sub>	Rated V <sub>R</sub> , square wave, 20 kHz, T <sub>C</sub> = 146 °C	6				
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		- 65 to 175	°C			

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 100 μΑ	200	-	-			
Forward voltage		I <sub>F</sub> = 3 A	-	-	1.0			
	V <sub>F</sub>	I <sub>F</sub> = 3 A, T <sub>J</sub> = 125 °C -		-	0.96	V		
		I <sub>F</sub> = 6 A	=	-	1.2			
		I <sub>F</sub> = 6 A, T <sub>J</sub> = 125 °C	-	-	1.13	1		
Reverse leakage current	I <sub>R</sub>	V <sub>R</sub> = V <sub>R</sub> rated	=	-	5			
		T <sub>J</sub> = 125 °C, V <sub>R</sub> = V <sub>R</sub> rated	=	-	250	μΑ		
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 200 V	-	12	-	pF		
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	=	8.0	-	nΗ		

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### VS-MURD620CT-M3

# Vishay Semiconductors Ultrafast Rectifier, 2 x 3 A FRED Pt®



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1.0 A, dI_F/dt =$	$I_F = 1.0 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	35		
Reverse recovery time		I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1.0 A, I <sub>REC</sub> = 0.25 A		-	-	25		
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C	$I_F = 3 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 160 \text{ V}$	-	19	-	ns	
		T <sub>J</sub> = 125 °C		-	26	-		
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	3.1	-	Α	
		T <sub>J</sub> = 125 °C		-	4.6	-	^	
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	30	-	nC	
		T <sub>J</sub> = 125 °C		-	60	-		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 65	-	175	°C	
Thermal resistance, junction to case per leg	R <sub>thJC</sub>		-	-	9.0		
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>		-	-	80	°C/W	
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	-	-		
\Maight			-	0.3	-	g	
Weight			-	0.01	-	oz.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Marking device		Case style D-PAK		MURE	620CT		



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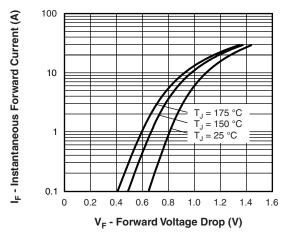


Fig. 1 - Typical Forward Voltage Drop Characteristics

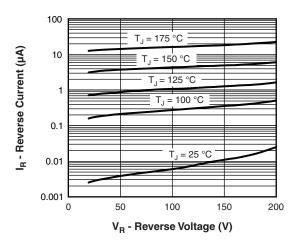


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

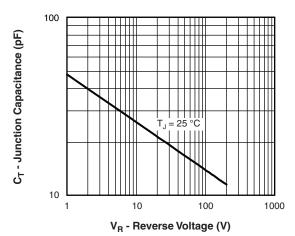


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

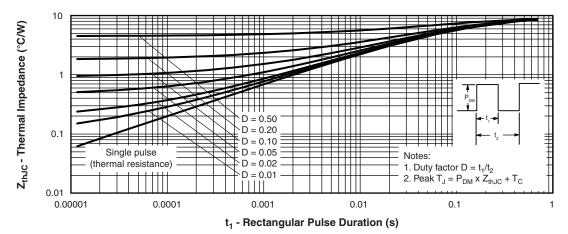


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

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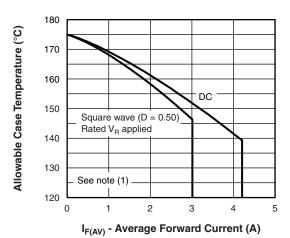


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

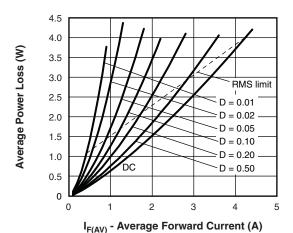


Fig. 6 - Forward Power Loss Characteristics

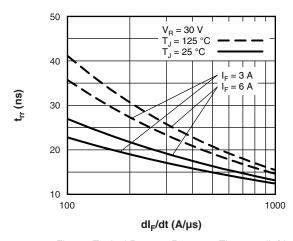


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

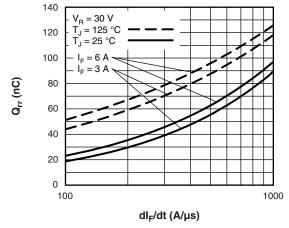


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note

 $^{(1)}$  Formula used:  $T_{C} = T_{J}$  - (Pd + Pd\_{REV}) x  $R_{thJC};$ Pd = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);  $Pd_{REV}$  = Inverse power loss =  $V_{R1} \times I_{R} (1 - D)$ ;  $I_{R}$  at  $V_{R1}$  = Rated  $V_{R1}$ 



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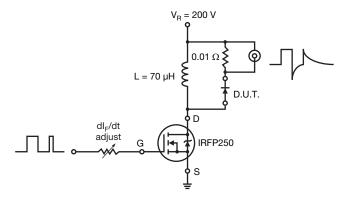
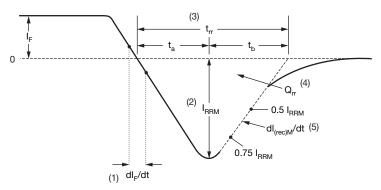


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dl<sub>F</sub>/dt rate of change of current through zero crossing
- (2)  $I_{RRM}$  peak reverse recovery current
- (3) t<sub>rr</sub> reverse recovery time measured from zero crossing point of negative going  $I_F$  to point where a line passing through 0.75  $I_{RRM}$  and 0.50  $I_{RRM}$ extrapolated to zero current.
- (4) Q<sub>rr</sub> area under curve defined by t<sub>rr</sub> and I<sub>RRM</sub>

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5)  $dI_{(rec)M}/dt$  - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

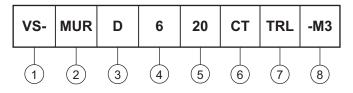
Fig. 10 - Reverse Recovery Waveform and Definitions

# Vishay Semiconductors Ultrafast Rectifier, 2 x 3 A FRED Pt®



#### **ORDERING INFORMATION TABLE**

**Device code** 



Vishay Semiconductors product

Ultrafast MUR series

D = D-PAK

Current rating (6 = 6 A)

Voltage rating (20 = 200 V)

TR = Tape and reel CT = Center tap (dual)

TRL = Tape and reel (left oriented) Tape and reel suffix TRR = Tape and reel (right oriented)

Environmental digit:

-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

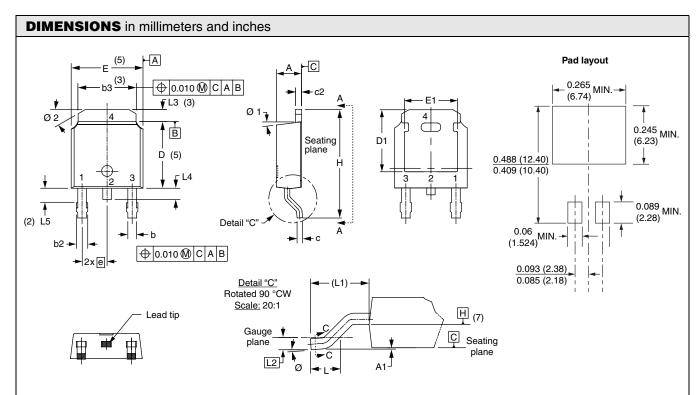
ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-MURD620CT-M3	75	3000	Antistatic plastic tube				
VS-MURD620CTTR-M3	2000	2000	13" diameter reel				
VS-MURD620CTTRL-M3	3000	3000	13" diameter reel				
VS-MURD620CTTRR-M3	3000	3000	13" diameter reel				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95016				
Part marking information	www.vishay.com/doc?95176				
Packaging information	www.vishay.com/doc?95033				



### Vishay High Power Products

## **D-PAK (TO-252AA)**



SYMBOL	MILLIM	ETERS	INC	NOTES	
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	2.18	2.39	0.086	0.094	
A1	-	0.13	-	0.005	
b	0.64	0.89	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	3
С	0.46	0.61	0.018	0.024	
c2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	5
D1	5.21	-	0.205	-	3
Е	6.35	6.73	0.250	0.265	5
E1	4.32	-	0.170	-	3

SYMBOL	MILLIMETERS		INC	NOTES	
STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
е	2.29 BSC		0.090	0.090 BSC	
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74	2.74 BSC		0.108 REF.	
L2	0.51	BSC	0.020 BSC		
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2
Ø	0°	10°	0°	10°	
Ø1	0°	15°	0°	15°	
Ø2	25°	35°	25°	35°	

#### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- $^{(7)}$  Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC outline TO-252AA



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